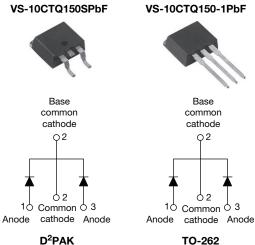


**Vishay Semiconductors** 

# High Performance Schottky Rectifier, 2 x 5 A



TO-262

PRODUCT SUMMARY				
Package	D <sup>2</sup> PAK, TO-262			
I <sub>F(AV)</sub>	2 x 5 A			
V <sub>R</sub>	150 V			
V <sub>F</sub> at I <sub>F</sub>	0.93 V			
I <sub>RM</sub>	7 mA at 125 °C			
T <sub>J</sub> max.	175 °C			
Diode variation	Common cathode			
E <sub>AS</sub>	5 mJ			

#### **FEATURES**

- 175 °C T<sub>J</sub> operation
- · Center tap configuration
- · Low forward voltage drop
- High frequency operation
- RoHS • High purity, high temperature epoxy COMPLIANT HALOGEN encapsulation for enhanced mechanical FREE strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

## DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I <sub>F(AV)</sub>	Rectangular waveform	10	А			
V <sub>RRM</sub>		150	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	620	А			
V <sub>F</sub>	5 $A_{pk}$ , $T_J$ = 125 °C (per leg)	0.73	V			
TJ	Range	-55 to +175	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-10CTQ150SPbF VS-10CTQ150-1PbF	UNITS		
Maximum DC reverse voltage	V <sub>R</sub>	150	V		
Maximum working peak reverse voltage	V <sub>RWM</sub>	150	V		

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average per leg			5	•		
forward current, see fig. 5 per device	I <sub>F(AV)</sub>	50 % duty cycle at $T_C$ = 155 °C, rectangular waveform		10	A	
Maximum peak one cycle non-repetitive	I <sub>FSM</sub>	5 µs sine or 3 µs rect. pulse	Following any rated load	620	А	
surge current per leg, see fig. 7		10 ms sine or 6 ms rect. pulse	condition and with rated V <sub>RRM</sub> applied	115		
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 10 mH		5	mJ	
Repetitive avalanche current per leg	eg $I_{AR}$ Current decaying linearly to zero in 1 µs Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		1	А		

Revision: 20-May-14

Document Number: 94116

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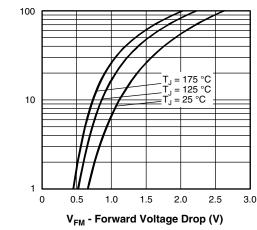
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
		5 A	T <sub>1</sub> = 25 °C	0.93	V	
Maximum forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	10 A	1j=25 0	1.10		
See fig. 1	VFM ()	5 A	T <sub>1</sub> = 125 °C	0.73		
		10 A	1j = 125 C	0.86		
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C		0.05	mA	
See fig. 2		T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>R</sub>	7		
Threshold voltage	V <sub>F(TO)</sub>	T T movimum		0.468	V	
Forward slope resistance	r <sub>t</sub>	$T_J = T_J$ maximum		28	mΩ	
Maximum junction capacitance per leg	CT	$V_R$ = 5 $V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		200	pF	
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 mm from package body		8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs	

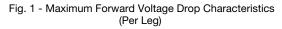
#### Note

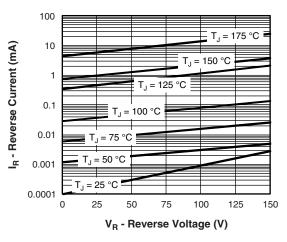
 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

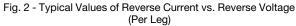
THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C	
Maximum thermal resistance, junction to case per leg		P	DC operation	3.50		
Maximum thermal resistance, junction to case per package		nthJC	R <sub>thJC</sub> DC operation	1.75	°C/W	
Typical thermal resistance, case to heatsink (only for T	Typical thermal resistance, case to heatsink (only for TO-220)		Mounting surface, smooth and greased	0.50		
Approximate weight				2	g	
Approximate weight	Approximate weight			0.07	oz.	
Mounting torque	minimum			6 (5)	kgf · cm	
	maximum			12 (10)	(lbf · in)	
Marking davice	Marking device		Case style D <sup>2</sup> PAK	10CTQ1	50S	
			Case style TO-262	10CTQ1	50-1	











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## VS-10CTQ150SPbF, VS-10CTQ150-1PbF

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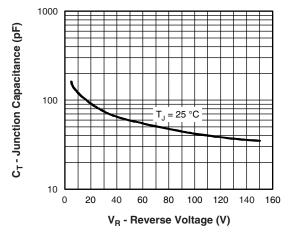


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

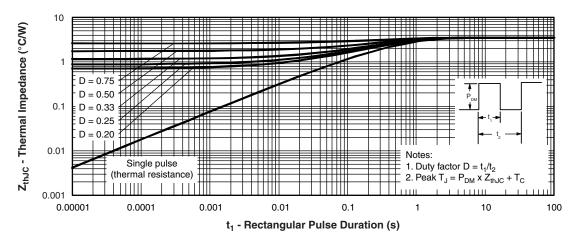


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

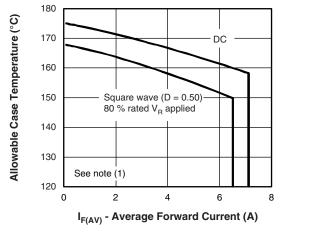


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

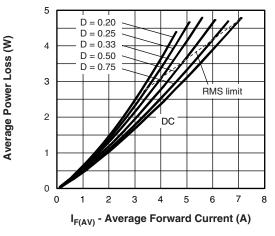


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

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## VS-10CTQ150SPbF, VS-10CTQ150-1PbF

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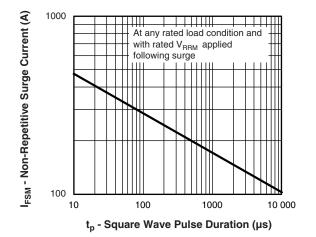


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

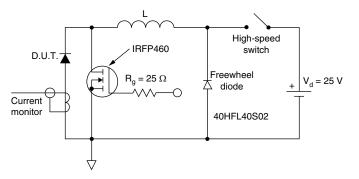


Fig. 8 - Unclamped Inductive Test Circuit

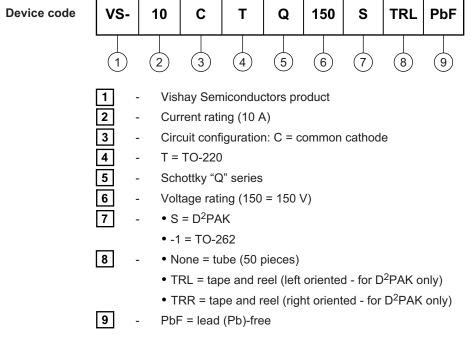
#### Note

 $^{(1)}$  Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC};$ Pd = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6); Pd\_{REV} = Inverse power loss =  $V_{R1} \times I_R (1 - D); I_R$  at  $V_{R1} = 10 \text{ V}$  VS-С т PbF 10 Q 150 S TRL

**Vishay Semiconductors** 

## **ORDERING INFORMATION TABLE**

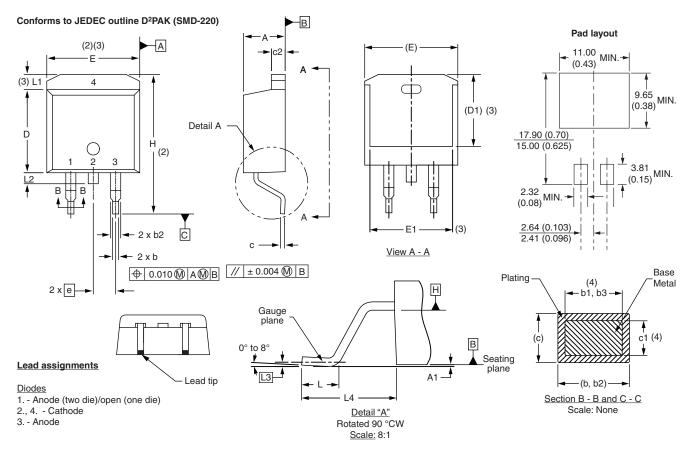
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Packaging information	www.vishay.com/doc?95032			

**Vishay Semiconductors** 

# D<sup>2</sup>PAK, TO-262



## DIMENSIONS - D<sup>2</sup>PAK in millimeters and inches

SHA

SYMBOL	MILLIN	IETERS	INC	NOTES	
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
с	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

#### Notes

- $^{(1)}\,$  Dimensioning and tolerancing per ASME Y14.5 M-1994  $\,$
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$  Thermal pad contour optional within dimension E, L1, D1 and E1
- <sup>(4)</sup> Dimension b1 and c1 apply to base metal only
- <sup>(5)</sup> Datum A and B to be determined at datum plane H
- <sup>(6)</sup> Controlling dimension: inch

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NULES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

(7) Outline conforms to JEDEC outline TO-263AB

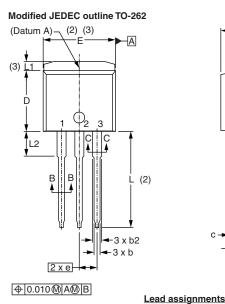
# **Outline Dimensions**

## **Vishay Semiconductors**

D<sup>2</sup>PAK, TO-262



### **DIMENSIONS - TO-262** in millimeters and inches

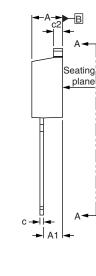


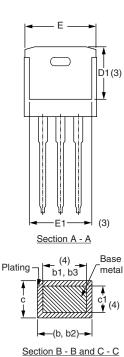
Lead tip

Diodes

3. - Anode

2., 4. - Cathode





Scale: None MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 4.06 4.83 0.160 0.190 А A1 2.03 3.02 0.080 0.119 b 0.51 0.99 0.020 0.039 0.51 0.89 0.020 0.035 4 b1 h2 1.14 1.78 0.045 0.070 b3 1.14 1.73 0.045 0.068 4 0.38 0.74 0.015 0.029 С 0.38 0.58 0.015 0.023 4 c1 1.14 0.045 0.065 c2 1.65 D 8.51 9.65 0.335 0.380 2 0.270 D1 6.86 8.00 0.315 3 Е 9.65 10.67 0.380 0.420 2, 3 E1 7.90 8.80 0.311 0.346 3 е 2.54 BSC 0.100 BSC L 13.46 14.10 0.530 0.555 L1 1.65 0.065 -3 L2 3.56 3.71 0.140 0.146 Notes

1. - Anode (two die)/open (one die)

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline

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